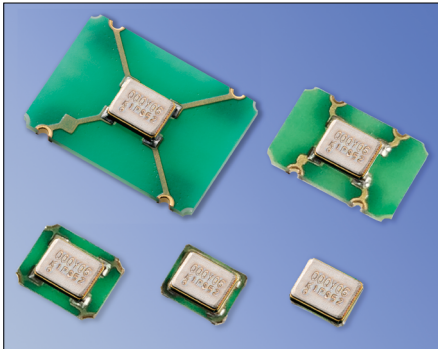




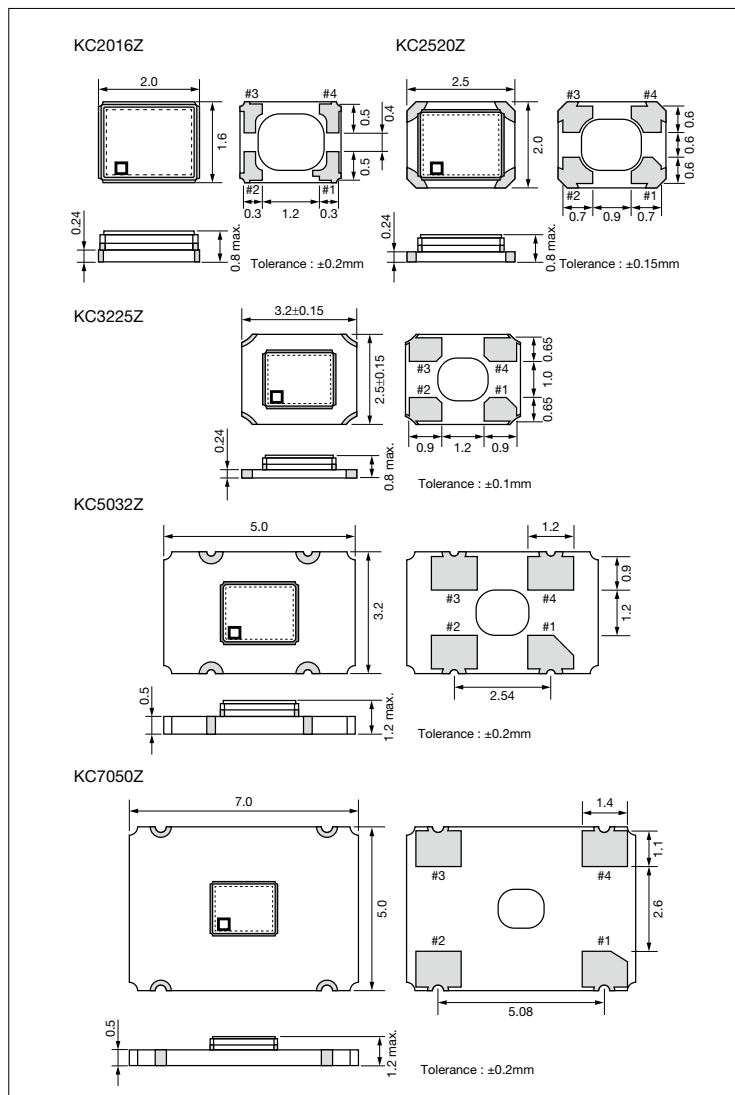
CMOS/ 1.8V, 2.5V, 3.3V/ 2.0×1.6, 2.5×2.0, 3.2×2.5, 5.0×3.2, 7.0×5.0mm



RoHS Compliant

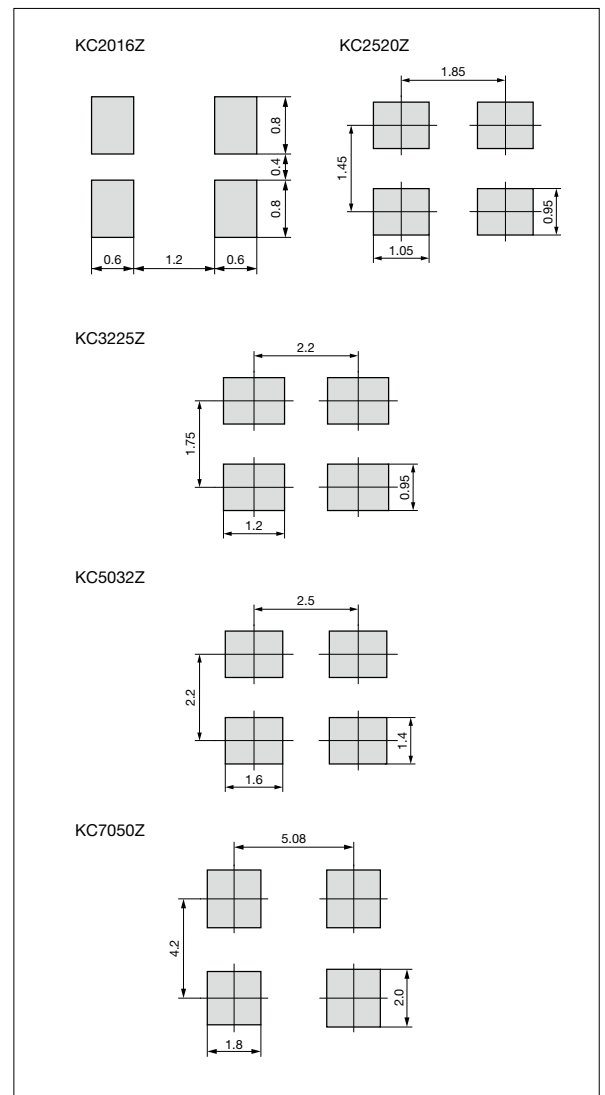
Dimensions

(Unit : mm)



Recommended Land Patterns

(Unit : mm)

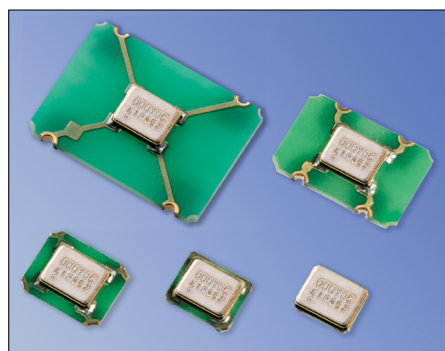


Pad Connections	
#1	Stand-by Function
#2	Case GND
#3	Output
#4	Vcc

Stand-by Function	
Pad1	Pad3 (Output)
Open	Active
"H" Level	Active
"L" Level	High Z (No-Oscillation)



CMOS/ 1.8V, 2.5V, 3.3V / 2.0×1.6, 2.5×2.0, 3.2×2.5, 5.0×3.2, 7.0×5.0mm



RoHS Compliant

Features

- Frequency Range 0.5 to 170 MHz
- CMOS Output
- Short Lead Time
- Heat resistant up to +125°C

Applications

- Consumer/ Networking/ Industrial/ Amuse

Table 1

Freq. Tol.	Operating Temperature Range (°C)	Note
Code × 10 ⁻⁶		
S ± 30	-10 to +70	For additional stability, please contact us.
U ± 25		
W ± 20		
G ± 50		
H ± 30	-40 to +85	
J ± 25		
K ± 20		
L ± 15		
6 ± 50	-40 to +105	
5 ± 30		
X ± 100	-40 to +125	
Z ± 50		
9 ± 30		

How to Order

KC□□□□Z 25.0000 C 1 □ X 00
① ② ③ ④ ⑤ ⑥ ⑦

①Series

KC2016Z	2016 Size	KC2520Z	2520 Size
KC3225Z	3225 Size	KC5032Z	5032 Size
KC7050Z	7050 Size		

②Output Frequency (25.0000 : 25MHz)

③Output Type (C : CMOS)

④Supply Voltage

(1 : 1.8V/ 2.5V/ 3.3V Compatible)

⑤Frequency Tolerance (See Table 1)

⑥Symmetry/ INH Function

X	STD 45/ 55%
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⑦Individual Specification

(STD Specification is "00")

Packaging Tape&Reel

KC7050Z/ KC5032Z	1000 pcs./ reel
KC3225Z/ KC2520Z/ KC2016Z	2000 pcs./ reel

Specifications

Item	Symbol	Conditions		Min.	Max.	Unit
Output Frequency Range	f _o			0.5	170	MHz
Frequency Tolerance	f _{tol}	Initial tolerance, Operating temperature range, Rated power supply voltage change, Load change, Aging (1 year @25°C), Shock and vibration		See Table 1.		
Storage Temperature Range	T _{stg}			-55	150	°C
Operating Temperature Range	T _{use}			See Table 1.		
Max. Supply Voltage	—			-0.3	4.5	V
Supply Voltage	V _{CC}			1.71	3.63	V
Current Consumption (Noload/ 1.71≤V _{CC} ≤2.25)	I _{CC}	0.5≤f _o <5MHz		—	5.2	mA
		5≤f _o <15MHz		—	5.8	
		15≤f _o <30MHz		—	6.2	
		30≤f _o <50MHz		—	6.8	
		50≤f _o ≤60MHz		—	6.8	
		60<f _o <75MHz		—	9	
		75≤f _o <105MHz		—	10	
		105≤f _o <130MHz		—	10.5	
		130≤f _o <160MHz		—	11.5	
Current Consumption (Noload/ 2.25<V _{CC} ≤2.8)	I _{CC}	160≤f _o ≤170MHz		—	12.5	
		0.5≤f _o <5MHz		—	5.5	
		5≤f _o <15MHz		—	6	
		15≤f _o <30MHz		—	6.5	
		30≤f _o <50MHz		—	7.2	
		50≤f _o ≤60MHz		—	7.4	
		60<f _o <75MHz		—	10	
		75≤f _o <105MHz		—	11.5	
		105≤f _o <130MHz		—	12.5	
Current Consumption (Noload/ 2.8<V _{CC} ≤3.63)	I _{CC}	130≤f _o <160MHz		—	14	
		160≤f _o ≤170MHz		—	15	
		0.5≤f _o <5MHz		—	5.8	
		5≤f _o <15MHz		—	6.5	
		15≤f _o <30MHz		—	7.3	
		30≤f _o <50MHz		—	8	
		50≤f _o ≤60MHz		—	8.5	
		60<f _o <75MHz		—	12.5	
		75≤f _o <105MHz		—	14.5	
Stand-by Current	I _{std}			—	5	μA
		@50% V _{CC}		45	55	
Symmetry	SYM					%
Rise/ Fall Time (20% to 80% Output Level)	Tr/ Tf	0.5≤f _o ≤60MHz	Loaded/ 1.71≤V _{CC} ≤2.25	—	4	ns
			Loaded/ 2.25<V _{CC} ≤2.8	—	3	
			Loaded/ 2.8<V _{CC} ≤3.63	—	2.5	
		60<f _o ≤170MHz	Loaded/ 1.71≤V _{CC} ≤2.25	—	1.5	
			Loaded/ 2.25<V _{CC} ≤2.8	—	1.3	
			Loaded/ 2.8<V _{CC} ≤3.63	—	1	
Low Level Output Voltage	V _{OL}	I _{OL} = 5mA			10% V _{CC}	V
High Level Output Voltage	V _{OH}	I _{OH} = -5mA	90% V _{CC}		—	V
Output Load (CMOS)	L _{CMOS}			—	15	pF
Low Level Input Voltage	V _{IL}			—	30% V _{CC}	V
High Level Input Voltage	V _{IH}			70% V _{CC}	—	V
Disable Time	t _{dis}			—	200	ns
Enable Time	t _{ena}			—	5	ms
Start-up Time	t _{str}	@Minimum operating voltage to be 0 sec.		—	5	ms

All electrical characteristics are defined at the maximum load and operating temperature range.